

DIGITRON SEMICONDUCTORS

MAC15(A) SERIES

SILICON BIDIRECTIONAL THYRISTORS

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).

Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak repetitive off-state voltage⁽¹⁾ ($T_J = -40$ to $+125^\circ\text{C}$) MAC15-4, MAC15A-4 MAC15-6, MAC15A-6 MAC15-8, MAC15A-8 MAC15-10, MAC15A-10	V_{DRM}	200 400 600 800	Volts
Peak gate voltage	V_{GM}	10	Volts
RMS on-state current (full sine wave, 50 to 60Hz, $T_C = 90^\circ\text{C}$)	I_{TRMS}	15	Amps
Circuit fusing considerations ($t = 8.3\text{ms}$)	I^2t	93	A^2s
Peak non-repetitive surge current (1 cycle, 60 Hz, $T_C = 80^\circ\text{C}$, preceded and followed by rated current)	I_{TSM}	150	Amps
Peak gate power ($T_C = 80^\circ\text{C}$, pulse width = $2\mu\text{s}$)	P_{GM}	20	Watts
Average gate power ($T_C = 80^\circ\text{C}$, $t = 8.3\text{ms}$)	$P_{\text{G(AV)}}$	0.5	Watts
Peak gate current	I_{GM}	2.0	Amps
Operating junction temperature range	T_J	-40 to +125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-40 to +150	$^\circ\text{C}$

Note 1: V_{DRM} for all types can be applied on a continuous basis. Blocking voltage shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Maximum	Unit
Thermal resistance, junction to case	R_{SJC}	2	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ and either polarity of MT2 to MT1 voltage, unless otherwise noted)

Characteristic	Symbol	Min	Typ.	Max	Unit
Peak blocking current (Rated $V_{\text{DRM}} @ T_J = 25^\circ\text{C}$) (Rated $V_{\text{DRM}} @ T_J = 125^\circ\text{C}$)	I_{DRM}	-	-	10	μA
		-	-	2	mA
Peak on-state voltage ($I_{\text{TM}} = 21\text{A}$ peak, pulse width = 1 to 2 ms, duty cycle $\leq 2\%$)	V_{TM}	-	1.3	1.6	Volts
Gate trigger current (continuous dc) ($V_D = 12\text{V}$, $R_L = 100\Omega$) MT2(+),G(+) MT2(+),G(-) MT2(-),G(-) MT2(-),G(+) "A" suffix only	I_{GT}	-	-	50	mA
		-	-	50	
		-	-	50	
		-	-	75	
Gate trigger voltage (continuous dc) ($V_D = 12\text{V}$, $R_L = 100\Omega$) MT2(+),G(+) MT2(+),G(-) MT2(-),G(-) MT2(-),G(+) "A" suffix only ($V_D = \text{Rated } V_{\text{DRM}}, R_L = 10\text{k}\Omega, T_J = 110^\circ\text{C}$) MT2(+), G(+); MT2(-), G(-); MT2(+), G(-) MT2(-), G(+) "A" suffix only	V_{GT}	-	0.9	2	
		-	0.9	2	
		-	1.1	2	
		-	1.4	2.5	
		0.2	-	-	
		0.2	-	-	

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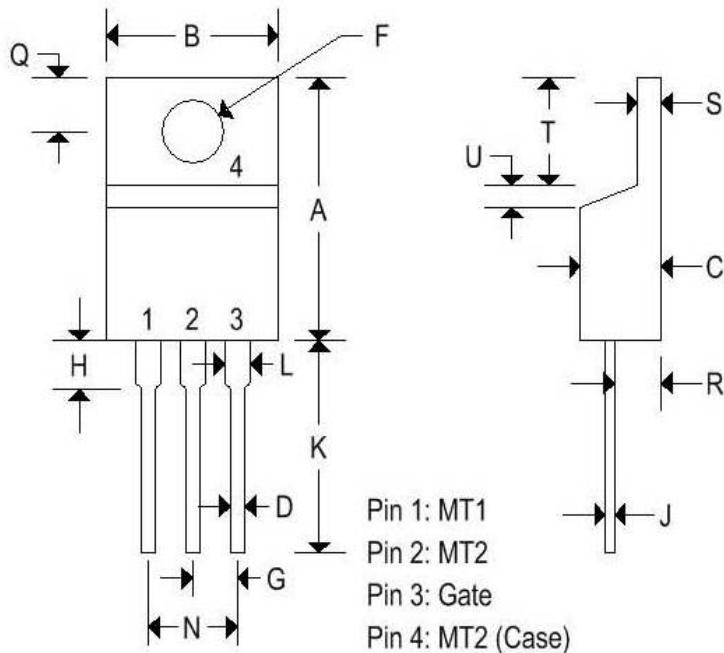
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Characteristic	Symbol	Min	Typ.	Max	Unit
Holding current (either direction) ($V_D = 12V$, gate open, $I_T = 200mA$)	I_H	-	6	40	mA
Turn on time ($V_D = \text{rated } V_{DRM}$, $I_{TM} = 17A$, $I_{GT} = 120mA$, rise time = $0.1\mu s$, pulse width = $2\mu s$)	t_{gt}	-	1.5	-	μs
Critical rate of rise of commutation voltage ($V_D = \text{Rated } V_{DRM}$, $I_{TM} = 21A$, commutating $di/dt = 7.6A/ms$, gate unenergized, $T_C = 80^\circ C$)	$dv/dt(c)$	-	5	-	$V/\mu s$

MECHANICAL CHARACTERISTIC

Case	TO-220AB
Marking	Body painted, alpha-numeric
Pin out	See below



	TO-220AB			
	Inches		Millimeters	
	Min	Max	Min	Max
A	0.575	0.620	14.600	15.750
B	0.380	0.405	9.650	10.290
C	0.160	0.190	4.060	4.820
D	0.025	0.035	0.640	0.890
F	0.142	0.147	3.610	3.730
G	0.095	0.105	2.410	2.670
H	0.110	0.155	2.790	3.930
J	0.014	0.022	0.360	0.560
K	0.500	0.562	12.700	14.270
L	0.045	0.055	1.140	1.390
N	0.190	0.210	4.830	5.330
Q	0.100	0.120	2.540	3.040
R	0.080	0.110	2.040	2.790
S	0.045	0.055	1.140	1.390
T	0.235	0.255	5.970	6.480
U	-	0.050	-	1.270
V	0.045	-	1.140	-
Z	-	0.080	-	2.030

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FIGURE 1 – RMS CURRENT DERATING

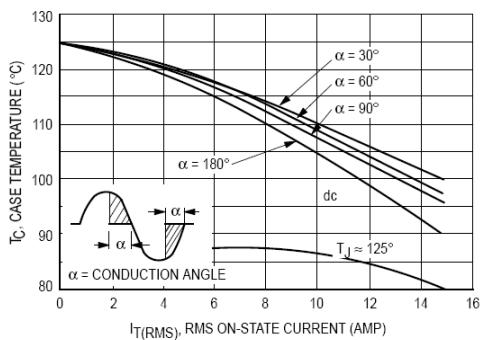


FIGURE 2 – ON-STATE POWER DISSIPATION

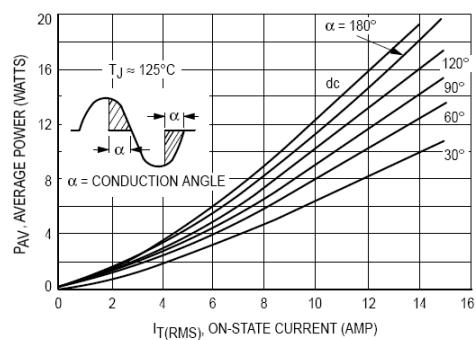


FIGURE 3 – TYPICAL GATE TRIGGER VOLTAGE

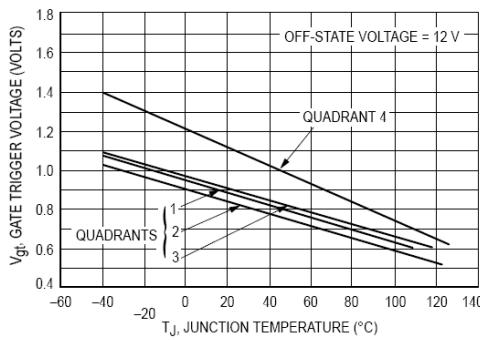


FIGURE 4 – TYPICAL GATE TRIGGER CURRENT

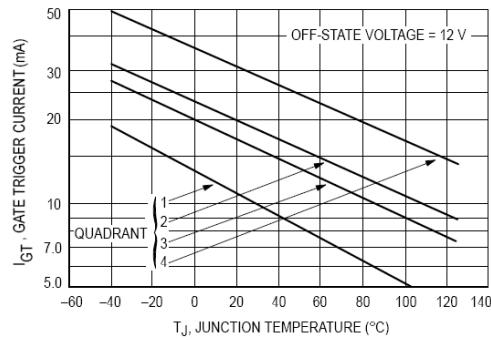


FIGURE 5 – ON-STATE CHARACTERISTICS

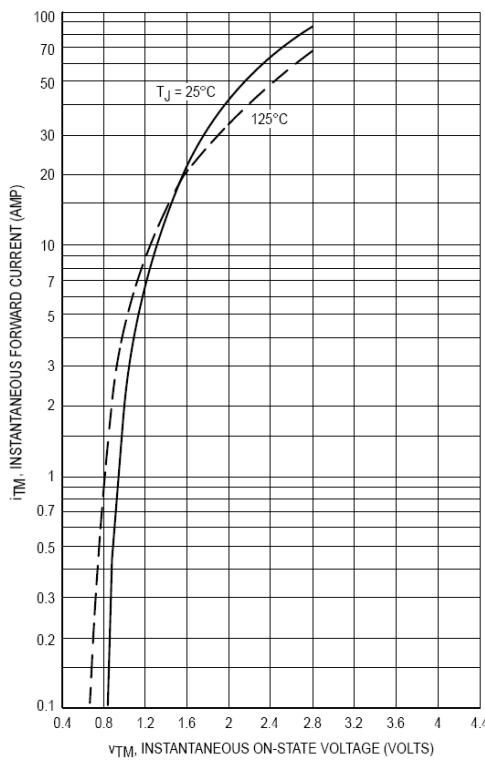


FIGURE 6 – TYPICAL HOLDING CURRENT

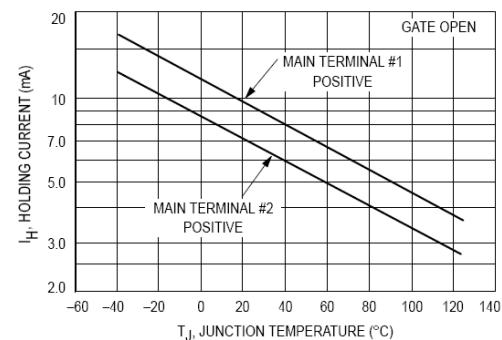


FIGURE 7 – MAXIMUM NON-REPETITIVE SURGE CURRENT

